





MMSZ5221B-MMSZ5267B ZENER DIODES



Features

- Planar Die Construction
- 500mW Power Dissipation
- 2.4V- 75V Standoff Voltage
- 5% Nominal Zener Voltage
- Designed for Surface Mount Application
- Plastic Material-UL Recognition Flammability Classification 94V-O
- This is a Halogen Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Mechanical Data

- Case: SOD-123, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202,

Method 208

- Polarity: Cathode Band
- Weight: 0.01 grams(approx)

Maximum Ratings @T_A=25°C unless otherwise specified

Characteristic	Symbol	Value	Units
Power Dissipation (Note 1)	P _D	500	mW
Forward Voltage (Note 2) @ I _F = 10mA	VF	0.9	V
Typical Thermal resistance junction to Ambient Air	Reja	357	°C/W
Operating Junction and Storage Temperature Range	T_{J} , T_{STG}	-55 to 150	°C

Notes: 1. Device mounted on ceramic PCB; 7.6 mm x 9.4 mm x 0.87 mm with pad areas 25 mm².

2. Tested with pulses, Tp≤1.0ms.









Electrical Characteristics @T_A=25°C unless otherwise specified

Type	Device		Vz (V) @I _{ZT}		I _{ZT}	Z _{ZT} @f _{ZT}	Z _{zk} @l _{zk}	Izk	I _R	V _R
Number	Marking	Nom(V)	Min(V)	Max(V)	Catons	~∑I.∞ı∑I	Q ZX WIZX	(mA)	uA)	(V)
MMSZ5221B	CI	2.4	2.28	2.52	mA 20	30	1200	0.25	100	1.0
MMSZ5221B	C3	2.7	2.57	2.84	20	30	1300	0.25	75	1.0
	C5	3.0	1000000	250000	20	'own'	1600	5380	50	70063.7
MMSZ5225B MMSZ5226B	GI	3.3	2.85	3.15	20	30 28	1600	0.25	25	1.0
MMSZ5227B	G2	3.6	3.42	3.78	20	24	1700	0.25	15	1.0
	G3	3.9		4.10	20	23	1900	0.25	10	1.0
MMSZ5228B MMSZ5229B	G4	4.3	3.71 4.09	4.10	20	22	2000	0.25	5	1.0
MMSZ5230B	G5	4.7	4.47	4.94	20	19	1900	0.25	5	2.0
MMSZ5230B	E1	5.1	4.85	5.36	20	17	1600	0.25	5	2.0
MMSZ5231B	E2	5.6	5.32	5.88	20	11	1600	0.25	5	3.0
	E3	6.0	1 2000 PM	0900000 0000000	20	7	A SORTING	000000	5	3.5
MMSZ5233B	05850	2000	5.70	6.30	200	100 July 1	1600	0.25	380	727000
MMSZ5234B	E4	6.2	5.89	6.51	20	7	1000	0.25	5	4.0
MMSZ5235B	E5	6.8	6.46	7.14	20	5	750	0.25	3	5.0
MMSZ5236B	FI	7.5	7.13	7.88	20	6	500	0.25	3	6.0
MMSZ5237B	F2	8.2	7.79	8.61	20	8	500	0.25	3	6.5
MMSZ5238B	F3	8.7	8.27	9.14	20	8	600	0.25	3	6.5
MMSZ5239B	F4	9.1	8.65	9.56	20	10	600	0.25	3	7.0
MMSZ5240B	F5	10	9.50	10.50	20	17	600	0.25	3	8.0
MMSZ5241B	н	11	10,45	11.55	20	22	600	0.25	2.0	8.4
MMSZ5242B	H2	12	11.40	12.60	20	30	600	0.25	1.0	9.1
MMSZ5243B	H3	13	12.35	13.65	9.5	13	600	0.25	0.5	9.9
MMSZ5244B	H4	14	13.30	14.70	9.0	15	600	0.25	0.1	10
MMSZ5245B	H5	15	14.25	15.75	8.5	16	600	0.25	0.1	11
MMSZ5246B	J1	16	15.20	16.80	7.8	17	600	0.25	0.1	12
MMSZ5247B	J2	17	16.15	17.85	7.4	19	600	0.25	01	13
MMSZ5248B	J3	18	17.10	18.90	7.0	21	600	0.25	0.1	14
MMSZ5250B	J5	20	19.00	21.00	6.2	25	600	0.25	0.1	15
MMSZ5251B	K1	22	20.90	23.10	5.6	29	600	0.25	0.1	17
MMSZ5252B	K2	24	22.80	25.20	5.2	33	600	0.25	0.1	18
MMSZ5253B	K3	25	23.75	26.25	5.0	35	600	0.25	0.1	19
MMSZ5254B	K4	27	25.65	28.35	5.0	41	600	0.25	0.1	21
MMSZ5255B	K5	28	26.60	29.40	4.5	44	600	0.25	0.1	21
MMSZ5256B	M1	30	28.50	31.50	4.2	49	600	0.25	0.1	23
MMSZ5257B	M2	33	31.35	34.65	3.8	58	700	0.25	0.1	25
MMSZ5258B	МЗ	36	34.20	37.80	3.4	70	700	0.25	0.1	27
MMSZ5259B	M4	39	37.05	40.95	3.2	80	800	0.25	0.1	30
MMSZ5260B	M5	43	40.85	45.15	3.0	93	900	0.25	0.1	33
MMSZ5261B	NI	47	44.65	49.35	2.7	105	1000	0.25	0.1	36
MMSZ5262B	N2	51	48.45	53.55	2.5	125	1100	0.25	0.1	39
MMSZ5263B	M8	56	53.2	58.8	2.2	150	1300	0.25	0.1	43
MMSZ5265B	N5	62	58.9	65.1	2.0	185	1400	0.25	0.1	47
MMSZ5267B	P2	75	71.25	78.75	1.7	270	1700	0.25	0.1	56

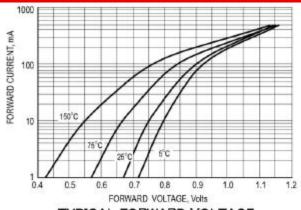
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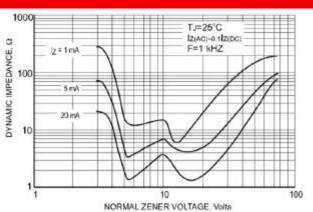






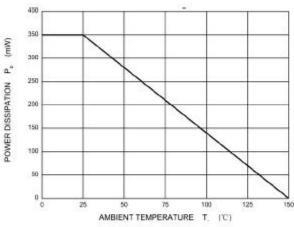


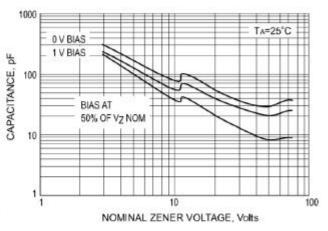




TYPICAL FORWARD VOLTAGE

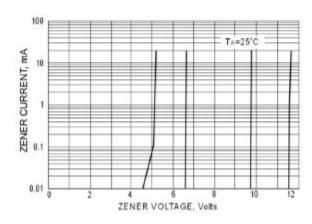


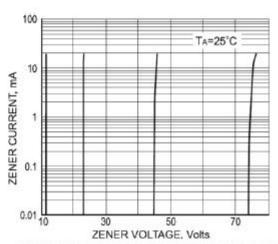




POWER DISSIPATION VS. AMBIENT TEMP

TYPICAL CAPACITANCE





ZENER BREAKDOWN CHARACTERISTICS

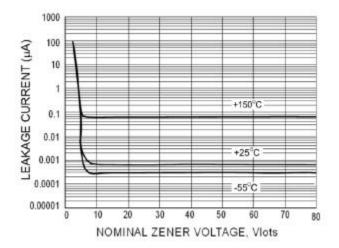
ZENER BREAKDOWN CHARACTERISTICS

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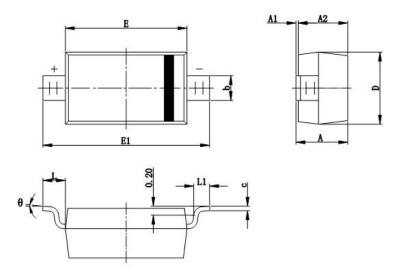






TYPICAL LEAKGE CURRENT

Mechanical Dimensions SOD-123



0)44501	Millin	neters	Inches		
SYMBOL	MIN.	MAX.	MIN.	MAX.	
Α	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.450	0.650	0.018	0.026	
С	0.080	0.150	0.003	0.006	
D	1.500	1.700	0.059	0.067	
Е	2.600	2.800	0.102	0.110	
E1	3.550	3.850	0.140	0.152	
L	0.500	REF.	0.020 REF.		
L1	0.250	0.450	0.010	0.018	
θ	0°	8°	0°	8°	

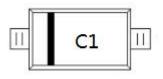
Note: If date code is before 2016 year, please contact with factory about marking.

Ordering Information

Device	Package	Shipping
MMSZ5221B- MMSZ5267B	SOD-123	3000pcs / reel
MMSZ5221BTR- MMSZ5267TR	SOD-123	3000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



C1 = Marking code

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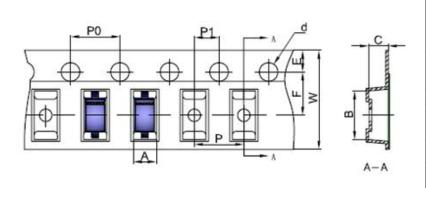








Carrier Tape Specification SOD-123



SYMBOL	Millimeters			
STWIBOL	Min.	Max.		
Α	1.80	1.90		
В	3.89	3.99		
С	1.52	1.62		
d	1.45	1.65		
E	1.65	1.85		
F	3.40	3.60		
Р	3.90	4.10		
P0	3.90	4.10		
P1	1.90	2.10		
W	7.90	8.30		

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